NSN 5961-01-044-3765

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-044-3765 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Component Name And Quantity:** 1 transistor and 1 semiconductor device diode **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage single transistor and 25.0 drain to substrate voltage single transistor and 25.0 source to substrate voltage single transistor and 30.0 gate to source voltage single transistor **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No